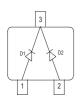


Silicon Variable Capacitance Diode

- For FM radio tuner with extended frequency band
- High tuning ratio at low supply voltage (car radio)
- Monolitic chip (common cathode) for perfect dual diode tracking
- Good linearity for C- V curve
- High figure of merit
- Pb-free (RoHS compliant) package



BB914



Туре	Package	Configuration	L _S (nH)	Marking
BB914	SOT23	common cathode	1.8	SM

Maximum Ratings at $T_A = 25^{\circ}$ C, unless otherwise specified

Parameter	Symbol	Value	Unit		
Diode reverse voltage	V _R	18	V		
Peak reverse voltage	V _{RM}	20			
$(R \ge 5 k\Omega)$					
Forward current	I _F	50	mA		
Operating temperature range	T _{op}	-55 125	°C		
Storage temperature	T _{stg}	-55 150			



Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics	·	·			
Reverse current	I _R				nA
V _R = 16 V		-	-	20	
<i>V</i> _R = 16 V, <i>T</i> _A = 85 °C		-	-	200	
AC Characteristics					
Diode capacitance	CT				pF
V _R = 2 V, <i>f</i> = 1 MHz		42.5	43.75	45	
V _R = 8 V, <i>f</i> = 1 MHz		17.6	18.7	19.75	
Capacitance ratio	C _{T2} /C _{T8}	2.28	2.34	2.42	
V _R = 2 V, V _R = 8 V, <i>f</i> = 1 MHz					
Capacitance matching ¹⁾	$\Delta C_{T}/C_{T}$	-	-	1.5	%
V _R = 2 V, V _R = 8 V, <i>f</i> = 1 MHz					
Series resistance	r _S	-	0.28	-	Ω
V _R = 2 V, <i>f</i> = 100 MHz					

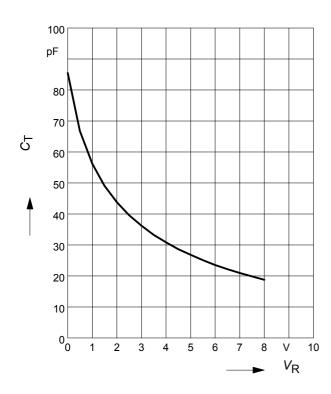
Electrical Characteristics at $T_A = 25^{\circ}$ C, unless otherwise specified

¹For details please refer to Application Note 047.



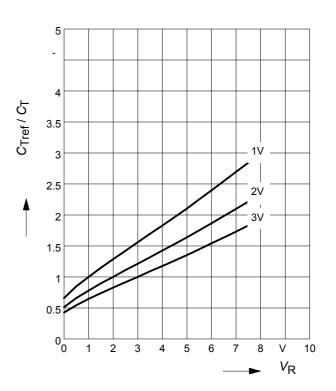
Diode capacitance $C_{T} = f (V_{R})$

f = 1 MHz

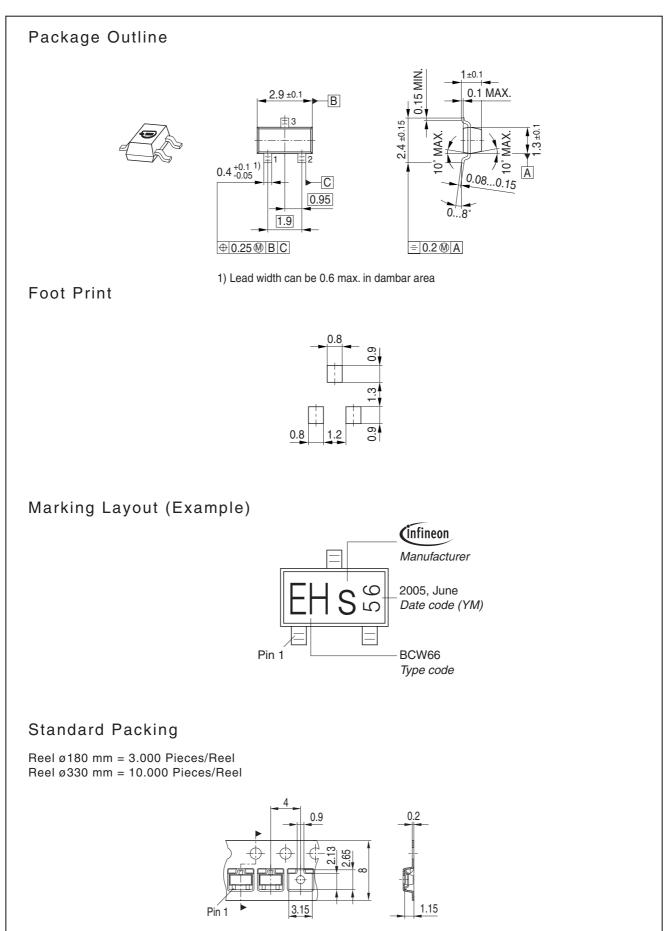


Capacitance ratio $C_{\text{Tref}}/C_{\text{T}} = f(V_{\text{R}})$

f = 1 MHz









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